. reescale Semiconductor Technical Data

CATV Amplifier Module

Features

- Specified for 77-, 110- and 128-Channel Loading
- Excellent Distortion Performance
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

Applications

- CATV Systems Operating in the 40 to 860 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications
- Output Stage Amplifier on Applications Requiring Low Power Dissipation

Description

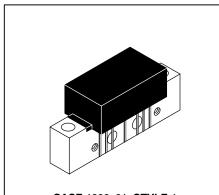
- 24 Vdc Supply, 40 to 860 MHz, CATV Forward Amplifier Module
- Replaced MHW8222B. There are no form, fit or function changes with this part replacement.
- **RoHS Compliant**

Document Number: MHW8222BN

Rev. 6, 4/2006

MHW8222BN

860 MHz **22.7 dB GAIN** 128-CHANNEL **CATV AMPLIFIER MODULE**



CASE 1302-01, STYLE 1

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DC Supply Voltage	V _{CC}	+28	Vdc
RF Input Voltage (Single Tone)	V _{in}	+70	dBmV
Operating Case Temperature Range	T _C	- 20 to +100	°C
Storage Temperature Range	T _{stg}	- 40 to +100	°C

Table 2. Electrical Characteristics ($V_{CC} = 24 \text{ Vdc}$, $T_C = +30^{\circ}\text{C}$, 75 Ω system unless otherwise noted)

Charac	Symbol	Min	Тур	Max	Unit	
Frequency Range		BW	40	_	860	MHz
Power Gain	f = 50 MHz f = 860 MHz	G _p	21.4 21.8	21.9 22.7	22.4 24	dB
Slope (f = 40 - 860 MHz)	S	0.1	0.8	1.5	_	
Gain Flatness (Peak To Valley)	(f = 40 - 860 MHz)	G _F	_	0.4	0.6	_
Input/Output Return Loss @ f = 40 MHz	IRL/ORL	20	24	_	dB	
Derate Return Loss @ f > 40 MHz	RLD	_	_	0.009	dB/MHz	
Composite Second Order (V _{out} = +38 dBmV/ch; 128 Channels) (V _{out} = +40 dBmV/ch; 110 Channels) (V _{out} = +44 dBmV/ch; 77 Channels)		CSO ₁₂₈ CSO ₁₁₀ CSO ₇₇	_ _ _	- 68 - 64 - 65	- 60 - 61 - 62	dBc



Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_{C} = +30°C, 75 Ω system unless otherwise noted) (continued)

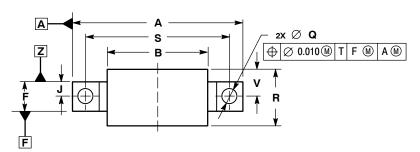
Characteristic	Symbol	Min	Тур	Max	Unit
Cross Modulation Distortion (V _{out} = +38 dBmV/ch, 128-Channel @ Fm = 55.25 MHz) (V _{out} = +40 dBmV/ch, 110-Channel @ Fm = 55.25 MHz) (V _{out} = +44 dBmV/ch, 77-Channel @ Fm = 55.25 MHz)	XMD ₁₂₈ XMD ₁₁₀ XMD ₇₇	_ _ _	- 65 - 63 - 59	- 63 - 60 - 56	dBc
Composite Triple Beat (V _{out} = +38 dBmV/ch, 128-Channels, Worst Case) (V _{out} = +40 dBmV/ch, 110-Channels, Worst Case) (V _{out} = +44 dBmV/ch, 77-Channels, Worst Case)		_ _ _	- 66 - 64 - 65	- 64 - 61 - 62	dBc
Noise Figure f = 50 MHz f = 750 MHz f = 860 MHz	NF	_ _ _	3.7 5 5.6	4.5 6.5 7	dB
DC Current	I _{DC}	180	220	240	mA

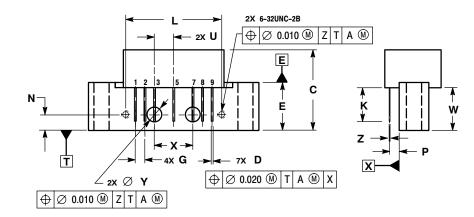
ARCHIVE INFORMATION



ARCHIVE INFORMATION

PACKAGE DIMENSIONS





- NOTES:
 1. DIMENSIONS ARE IN INCHES.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

1		INC	HES	MILLIMETERS			
1	DIM	MIN	MAX	MIN	MAX		
[Α		1.775		45.085		
	В		1.085		27.559		
	С		0.840		21.336		
	D	0.015	0.021	0.381	0.533		
	Е	0.465	0.510	11.811	12.954		
	F	0.300	0.325	7.62	8.255		
	G	0.100	BSC	2.540 BSC			
l	J	0.156 BSC		3.962 BSC			
	K	0.315	0.355	8.001	9.017		
	L	1.000	BSC	25.400 BSC			
l	N	0.165 BSC		4.191 BSC			
Į	P	0.100	BSC	2.540	BSC		
Į	Q	0.148	0.168	3.759	4.267		
l	R		0.600		15.24		
ı	S	1.500 BSC		38.100 BSC			
ı	U	0.200	200 BSC 5.08		BSC		
l	٧		0.250		6.350		
	W	0.435		11.049			
	X	0.400	BSC	10.16	D BSC		
	Y	0.152	0.163	3.861	4.140		
	Z	0.009	0.011	0.229	0.279		

- STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT

CASE 1302-01 ISSUE E

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